NSN 5962-01-265-8175

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View Online at https://aerobasegroup.com/nsn/5962-01-265-8175 **Body Length:** 0.840 inches **Body Width:** 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and dynamic and w/enable and w/strobe **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 13 input **Case Outline Source And Designator:** D-2 mil-m-38510 **Current Rating Per Characteristic:** 50.00 milliamperes output **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts total supply **Time Rating Per Chacteristic:** 150.00 nanoseconds propagation delay time, low to high level output and 150.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Ram **Memory Capacity:**

Unknown

Precious Material And Location:

Terminal surface option gold

Precious Material:

Gold

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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| Terminal | Type | Δnd | Quantity: | |
|----------------------------|-------|------|------------|--|
| ı C ı IIIIII aı | ı ype | Allu | Qualitity. | |

16 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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